## **SPTECH Silicon NPN Power Transistor**

## 2SC3834

### DESCRIPTION

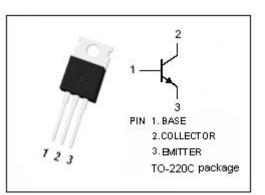
- Low Collector Saturation Voltage
  - : V<sub>CE(sat)</sub>= 0.5V(Max)@ I<sub>C</sub>=3A
- Collector-Emitter Breakdown Voltage-: V<sub>(BR)CEO</sub>= 120V (Min)
- Good Linearity of h<sub>FE</sub>

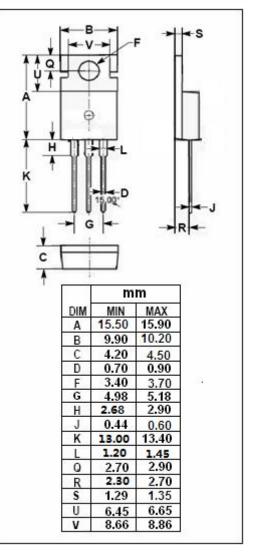
#### **APPLICATIONS**

• Designed for use in humidifier , DC/DC converter and general purpose applications

#### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CBO</sub>	Collector-Base Voltage	200	V
Vceo	Collector-Emitter Voltage	120	V
V <sub>EBO</sub>	Emitter-Base Voltage	8	V
lc	Collector Current-Continuous	7	A
Ісм	Collector Current-Pulse	14	А
I <sub>B</sub>	Base Current-Continuous	3	А
Pc	Collector Power Dissipation @ $T_c=25^{\circ}C$	50	W
TJ	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C





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### **ELECTRICAL CHARACTERISTICS**

#### T<sub>c</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 50mA ; I <sub>B</sub> = 0	120			V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 3A; I <sub>B</sub> = 0.3A			0.5	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 3A; I <sub>B</sub> = 0.3A			1.2	V
Ісво	Collector Cutoff Current	V <sub>CB</sub> = 200V; I <sub>E</sub> = 0			100	μA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 8V; I <sub>C</sub> = 0			100	μ Α
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 3A ; V <sub>CE</sub> = 4V	70		220	
f⊤	Current-Gain—Bandwidth Product	I <sub>E</sub> = -0.5A ; V <sub>CE</sub> = 12V	20			MHz
Сов	Output Capacitance	I <sub>E</sub> = 0 ; V <sub>CB</sub> = 10V;f <sub>test</sub> = 1.0MHz		110		pF

### Switching times

t <sub>on</sub>	Turn-on Time			0.5	μ <b>S</b>
t <sub>stg</sub>	Storage Time	I <sub>C</sub> = 3A ;I <sub>B1</sub> =0.3A; I <sub>B2</sub> = -0.6A R <sub>L</sub> = 16.7 Ω ; V <sub>CC</sub> = 50V		3.0	μs
t <sub>f</sub>	Fall Time			0.5	μs

### • h<sub>FE</sub> Classifications

0	Y	G
70-120	100-200	160-220

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